

# **BC184C**

# Silicon NPN Small Signal Transistor (Note 1)

- BV<sub>CEO</sub> = 30V (Min.)  $h_{FE}$  = 130 (Min.) @V<sub>CE</sub> = 5.0V,  $I_{C}$  = 100mA



1. Collector 2. Base 3. Emitter

## Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	45	V
V <sub>CEO</sub>	Collector-Emitter Voltage	30	V
$V_{EBO}$	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	500	mA
P <sub>C</sub>	Collector Dissipation (T <sub>a</sub> =25°C) (Note 2, 3)	350	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 55 ~ 150	°C

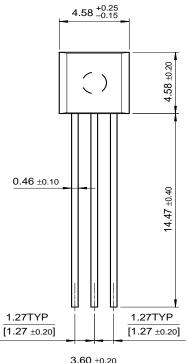
## Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

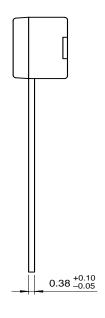
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV <sub>CBO</sub>	Collector-Base Voltage	$I_C = 10\mu A$	45			V
BV <sub>CEO</sub>	Collector-Emitter Voltage	I <sub>C</sub> = 2mA	30			V
BV <sub>EBO</sub>	Emitter-Base Voltage	$I_E = 10\mu A$	5			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = 30V			15	nA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = 4V			15	nA
h <sub>FE</sub>	DC Current Gain	$V_{CE} = 5V, I_{C} = 10\mu A$ $V_{CE} = 5V, I_{C} = 2mA$ $V_{CE} = 5V, I_{C} = 100mA$	100 250 130		800	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	$I_C = 10 \text{mA}, I_B = 0.5 \text{mA}$ $I_C = 100 \text{mA}, I_B = 5 \text{mA}$			0.6 0.25	V
V <sub>BE</sub> (sat)	Base-Emitter Saturation Voltage	I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA			1.2	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	$V_{CE} = 5V, I_{C} = 2mA$ 0.55			0.7	V
С <sub>ОВ</sub>	Output Capacitance	V <sub>CE</sub> = 10V, f = 1MHz		5	pF	
f <sub>T</sub>	Current gain Bandwidth Product	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA 150 f = 100MHz			MHz	
h <sub>FE</sub>	Small Signal Current Gain	V <sub>CE</sub> = 5V, I <sub>C</sub> = 2mA 240 f = 1KHz		900		
NF	Noise Figure	$V_{CE} = 5V, I_{C} = 200 mA$ $R_{G} = 2K\Omega, f = 30 Hz \sim 15 KHz$ $V_{CE} = 5V, I_{C} = 200 \mu A,$ $f = 1 KHz$			4	dB

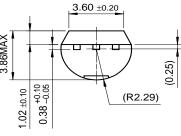
- These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.
   These ratings are based on a maximum junction temperature of 150degrees C.

# **Package Dimensions**

TO-92







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